Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.36$ V at $I_F = 5$ A



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PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 30 A				
V _{RRM}	100 V				
I _{FSM}	320 A				
V_F at I_F = 30 A (T_A = 125 °C)	0.66 V				
T _J max.	150 °C				
Package	TO-263AC (SMPD)				
Diode variations	Dual common cathode				

FEATURES

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available:
 Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, inductrial, and automotive application.

MECHANICAL DATA

Case: TO-263AC (SMPD)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test **Polarity:** As marked

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	V60D100C	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM}	100	V	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	60	٥	
	per diode		30	A	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load		I _{FSM}	320	А	
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +150	°C	

FREE



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F (1)	0.45	-	V	
	I _F = 15 A			0.62	-		
	I _F = 30 A			0.75	0.81		
	I _F = 5 A	T _A = 125 °C		0.36	-		
	I _F = 15 A			0.54	-		
	I _F = 30 A			0.66	0.73		
Reverse current at rated V_R per diode	V _R = 70 V	T _A = 25 °C	I _R (2)	12	-	μA	
		T _A = 125 °C		11	-	mA	
	$V_{\rm P} = 100 {\rm V}$	T _A = 25 °C		_	1000	μA	
		T _A = 125 °C		27	85	mA	

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 5 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	V60D100C	UNIT	
Typical thermal resistance	per diode	$R_{\theta JC}$	1.8	- °C/W	
	per device	$R_{\theta JC}$	0.95		
	per device	R _{0JM} ⁽²⁾	3		
	per device	R _{0JA} ⁽¹⁾⁽²⁾	45		

Notes

⁽¹⁾ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{0JA}$

 $^{(2)}$ Free air, without heatsink; thermal resistance $R_{\theta JA}$ - junction to ambient; thermal resistance $R_{\theta JM}$ - junction to mount

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AC (SMPD)	V60D100C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel	
TO-263AC (SMPD)	V60D100CHM3/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel	

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

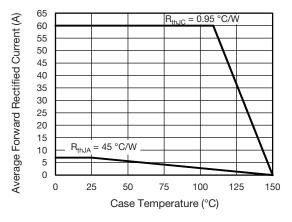


Fig. 1 - Forward Current Derating Curve

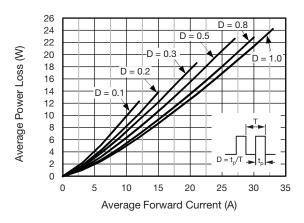


Fig. 2 - Forward Power Loss Characteristics Per Diode

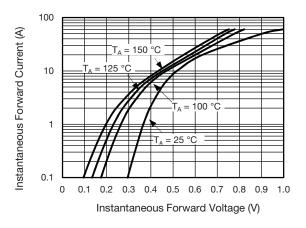


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

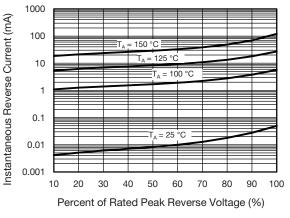


Fig. 4 - Typical Reverse Characteristics Per Diode

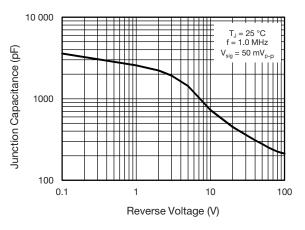


Fig. 5 - Typical Junction Capacitance Per Diode

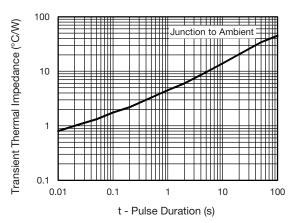


Fig. 6 - Typical Transient Thermal Impedance Per Device

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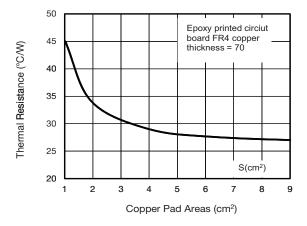
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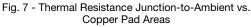
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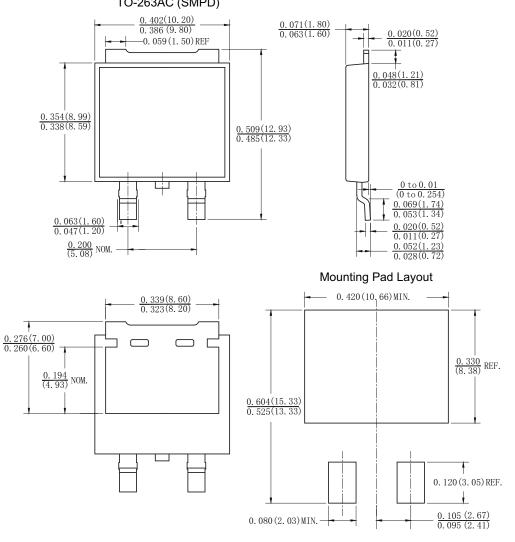


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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-263AC (SMPD)

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